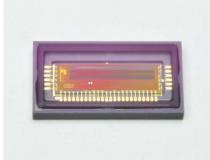


CMOS linear image sensor



S15611

40 MHz operation, digital output

The S15611 is a CMOS linear image sensor that has achieved a readout speed of 40 MHz max. and a line rate of 34 kHz max. The image sensor has a timing generator, bias generator, 12-bit A/D converter, and is easy to handle because of its digital I/O.

Features

- Pixel size: 7 × 200 μm
- **1024** pixels
- Effective photosensitive area length: 7.168 mm
- High-speed readout: 40 MHz max.
- Simultaneous integration of all pixels
- With variable integration time function (electronic shutter function)
- Single 3.3 V supply voltage operation
- SPI communication function (partial readout, offset adjustment)
- Built-in 12-bit A/D converter

Structure

Parameter	Specification	Unit
Number of pixels	1024	-
Pixel pitch	7	μm
Pixel height	200	μm
Effective photosensitive area length	7.168	mm
Package	Ceramic	-
Window material	Borosilicate glass	-

Absolute maximum ratings

Par	Parameter		Condition	Value	Unit
Supply voltage	Analog terminal	Vdd(A)	Ta=25 °C	-0.3 to +3.9	V
Supply voltage	Digital terminal	Vdd(D)	Ta=25 °C	-0.3 to +3.9	v
Digital input terminal voltage*1		Vi	Ta=25 °C	-0.3 to +3.9	V
Vref_cp1 terminal voltage		Vref_cp1	Ta=25 °C	-0.3 to +6.5	V
Vref_cp2 terminal	voltage	Vref_cp2	Ta=25 °C	-2.0 to +0.3	V
Operating tempera	Operating temperature		No dew condensation*2	-40 to +70	°C
Storage temperature		Tstg	No dew condensation*2	-40 to +70	°C
Soldering temperature*3		Tsol		260 (3 times)	°C

*1: MOSI, SCLK, CS, RSTB, MCLK, MST

*2: When there is a temperature difference between a product and the surrounding area in high humidity environment, dew condensation may occur on the product surface. Dew condensation on the product may cause deterioration in characteristics and reliability.
*3: Reflow soldering, JEDEC J-STD-020 MSL 4, see P.12

Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

- Applications
- Encoders
- Position detection
- Machine vision

Recommended terminal voltage (Ta=25 °C)

Para	ameter	Symbol	Min.	Тур.	Max.	Unit	
Supply voltage Analog terminal		Vdd(A)	3.15	3.3	3.6	V	
Supply voltage	Digital terminal	Vdd(D)	3.15	3.3	3.6	V	
Digital input	High level	Vi(H)	3	Vdd(D)	Vdd(D) + 0.25	V	
terminal voltage	Low level	Vi(L)	0	-	0.3	V	

Electrical characteristics [Ta=25 °C, Vdd(A)=Vdd(D)=3.3 V]

Parai	neter	Symbol	Min.	Тур.	Max.	Unit
Master clock pulse frequency		MCLK			40	MHz
Data rate		DR	-	f(MCLK)	-	MHz
Line rate*4	Line rate ^{*4}		-	-	34	kHz
Digital output valtage	High level	Vdo(H)	Vdd(D) - 0.25	Vdd(D)	-	M
Digital output voltage Low level		Vdo(L)	-	0	0.25	v
Current consumption	urrent consumption*5		-	120	150	mA

*4: When all pixels (1024 pixels) are read out

*5: f(MCLK)=40 MHz

Current consumption changes according to the master clock pulse frequency.

Electrical and optical characteristics [Ta=25 °C, Vdd(A)=Vdd(D)=3.3 V, f(MCLK)=40 MHz]

Parameter	Symbol	Min.	Тур.	Max.	Unit
Spectral response range	λ		400 to 1000		nm
Peak sensitivity wavelength	λр	-	700	-	nm
Photosensitivity*6	Sw	-	980	-	$V/(lx \cdot s)$
Photosensitivity *	5₩	-	2000 k	-	DN/(lx·s)
Conversion efficiency	CE	-	40	-	µV/e⁻
Photoresponse nonuniformity*7	PRNU	-	±5	±10	%
Dark output ^{*8}	VD	-	1.2	12	mV
	VD	-	2.5	25	DN
Saturation charge	Qsat	37	43	-	ke⁻
Saturation output	Vsat	1.47	1.71	-	V
Saturation output	VSdL	3000	3500	-	DN
Readout noise*9	Nread	-	0.63	1.9	mV rms
Reducut hoise"	Nreau	-	1.3	3.9	DN rms
Dynamic range ^{*10}	Drange	-	2700	-	-
Output offset ^{*11}	Voffset	0.122	0.244	0.366	V
Output onset	voliset	250	500	750	DN
Image lag ^{*12}	Lag	-	-	0.1	%

*6: 2856 K, tungsten lamp

*7: Photoresponse nonuniformity (PRNU) is the output nonuniformity that occurs when the entire photosensitive area is uniformly illuminated by light which is 50% of the saturation exposure level. PRNU is measured using 1018 pixels excluding the 3 pixels at both ends, and is defined as follows:

 $PRNU=\Delta X/X \times 100$ [%]

X: average output of all pixels, ΔX : difference between the maximum or minimum output and X

*8: Ts=10 ms, difference from the offset output

*9: Dark state

*10: Vsat/Nread

*11: Initial value. The offset level can be changed through the SPI.

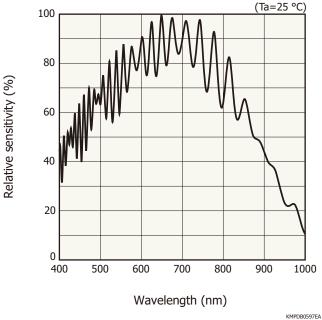
*12: If output of the previous frame exceeds the saturation output, it is the signal that remains in the next frame.



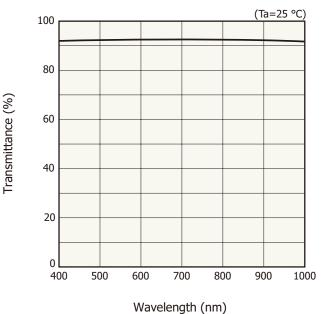
Electrical and optical characteristics [A/D converter, Ta=25 °C, Vdd(A)=Vdd(D)=3.3 V]

Parameter	Symbol	Value	Unit
Resolution	RESO	12	bit
Conversion time	tCON	1/f(MCLK)	S
Conversion voltage range	-	0 to 2	V



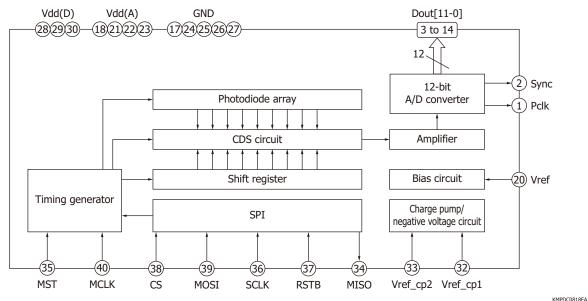


Spectral transmittance characteristics of window material (typical example)



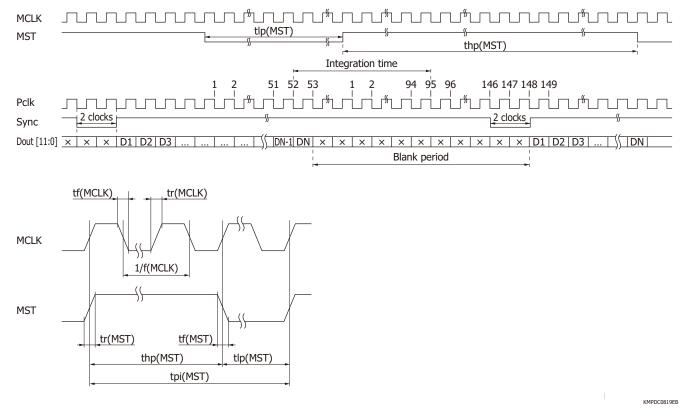
KMPDB0585EA

Block diagram





Timing chart



Parameter	Symbol	Min.	Тур.	Max.	Unit
Master start pulse period*13 *14	tpi(MST)	1162/f(MCLK)	-	-	S
Master start pulse high period	thp(MST)	167/f(MCLK)	-	-	S
Master start pulse low period*15	tlp(MST)	64/f(MCLK)	-	-	S
Master start pulse rise and fall times	tr(MST), tf(MST)	-	5	7	ns
Master clock pulse duty	-	45	50	55	%
Master clock pulse rise and fall times	tr(MCLK), tf(MCLK)	-	5	7	ns

*13: When 1024 pixels are read out

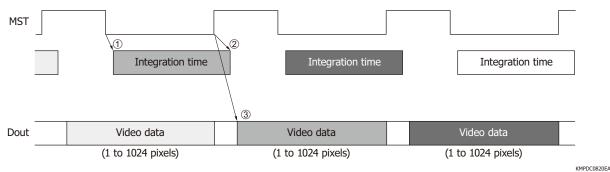
*14: The period is (138 + N)/f(MCLK) when N pixels are read out.

*15: The integration time corresponds to the low period of the master start pulse + 43 cycles of MCLK. The integration time can be changed by changing the ratio of the high and low periods of master start pulse. If the first Pclk after the master start pulse goes high is assumed to be the first edge, the video signal output is started at the 148th falling edge of Pclk. Since the start of the video output is simultaneous with the rising edge of Sync, acquire the video signal in reference to Sync.



Description of operation

The integration time is determined by the low period of the master start pulse.



.....

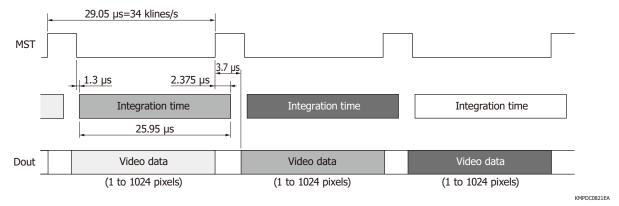
The start of integration time is determined by the falling edge of the master start pulse.

② The end of integration time is determined by the rising edge of the master start pulse.

③ Video data is output after the rising edge of the master start pulse. Video data is output in order from the first pixel. Note: Signal integration is possible even during video data output.

Operation example

Line rate=34 klines/s, master start pulse frequency=40 MHz, maximum integration time



· Master start pulse period=1162/f(MCLK)=29.05 μs (line rate is reciprocal of start pulse period)

 Master start pulse low period=Master start pulse period - Minimum period of master start pulse high period =1162/f(MCLK) - 167/f(MCLK)=1162/40 MHz - 167/40 MHz=995/40 MHz=24.875 µs

• Integration time=Master start pulse low period + Master clock pulse 43 cycles=(995 + 43)/40 MHz=25.95 μ s Sync rises approximately 3.7 μ s after the rising edge of the master start pulse. Then the video output signal is output in order from the first pixel.



Address	Register	Initial	value	Setting			
(decimal)	Register	Binary	Decimal	Setting			
1	Mode[0]	0	0	Operation mode setting Mode[0]=0: normal mode Mode[0]=1: low-power consumption mode			
11	Win_S[10:8]	000	0	Readout start pixel (11-bit)			
12	Win_S[7:0]	0000 0000	0	(Initial setting: 0)			
15	Win_W[10:8]	100	1024	Number of readout pixels (11-bit)			
16	Win_W[7:0]	0000 0000	1024	(Initial setting: 1024)			
18	SubsH[1:0]	00		Number of skipped pixels (2-bit) (Initial setting: 0)			
22	Offset[3:0]	0111	7	Offset shift (4-bit) (Initial setting: 7)			

SPI (serial peripheral interface) address

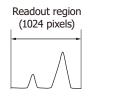
Note: Be sure to set the addresses shown in the above table. Setting to the addresses not shown in the above table may cause malfunction.

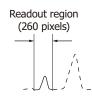
Setting the partial readout region

The partial readout region can be specified at the pixel level. The line rate can be increased by reducing the number of readout pixels.

All-pixel readout mode example

Partial readout mode example





The readout region can be specified at the pixel level.

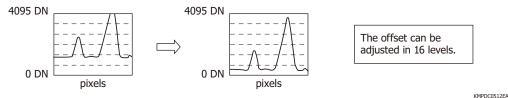
The maximum line rate=34 kline/s

The maximum line rate=100 kline/s

KMPDC0822EA

Setting the offset

The offset can be adjusted in 16 levels. The conversion range of the A/D converter can be used effectively by setting the appropriate offset.



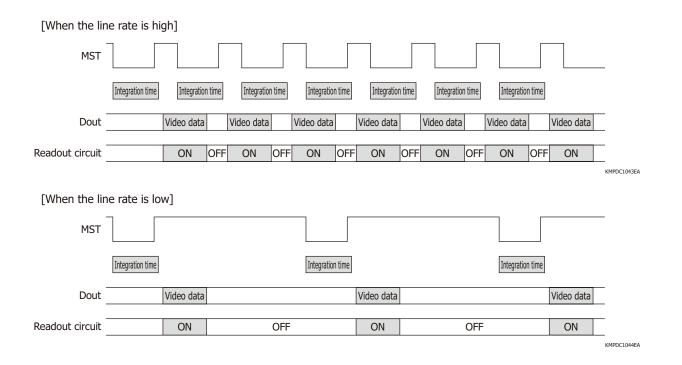
Low-power consumption mode

Power consumption can be lowered when the line rate is low. Electrical and optical characteristics besides current consumption are the same in normal mode and low-power consumption mode.

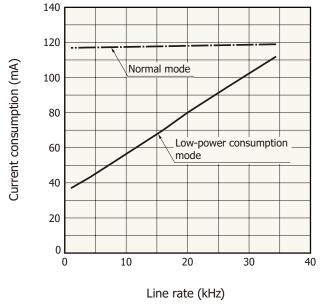


Operation explanation of low-power consumption mode

In low-power consumption mode, the operation of the readout circuit is stopped except during the video data readout period. Therefore, current consumption can be reduced when the line rate is low.



Line rate vs. current consumption (typical example)

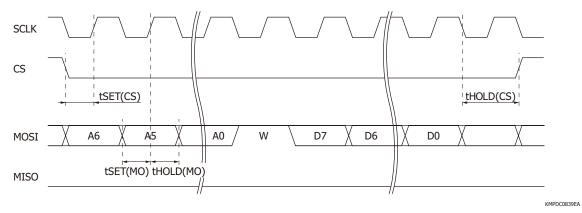


KMPDB0696EA



- Setting using the SPI

Set the SPI using SCLK, CS, and MOSI. Changing RSTB to low level resets all parameters to the initial settings.



[Ta=25 °C, Vdd(A)=Vdd(D)=Vdd(C)=3.3 V]

Parameter	Symbol	Min.	Тур.	Max.	Unit
SPI clock pulse frequency	f(SCLK)	-	7.5	10	MHz
SPI setup time (CS)	tSET(CS)	7	-	-	ns
SPI hold time (CS)	tHOLD(CS)	7	-	-	ns
SPI setup time (MOSI)	tSET(MO)	7	-	-	ns
SPI hold time (MOSI)	tHOLD(MO)	7	-	-	ns
Digital input signal rise time* ¹⁶	tr(sigi)	-	5	7	ns
Digital input signal fall time*16	tf(sigi)	-	5	7	ns

*16: Time for the input voltage to rise or fall between 10% and 90%

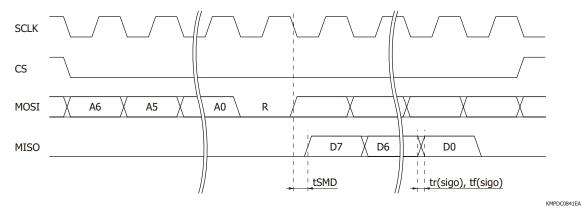
Setting example

Set Win	_S[7:0]=	8															
SCLK																		-
CS																		-
MOSI		0	0	0	1	1	0	0	1	0	0	0	0	1	0	0	0	[
		A6	A5	A4	A3	A2	A1	A0	W	D7	D6	D5	D4	D3	D2	D1	D0	
MISO																		_
																		KMPDC0840EA



Confirm SPI settings

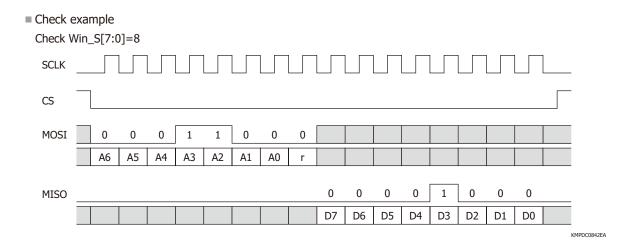
You can check the current SPI settings in the following manner.



[Ta=25 °C, Vdd(A)=Vdd(D)=Vdd(C)=3.3 V]

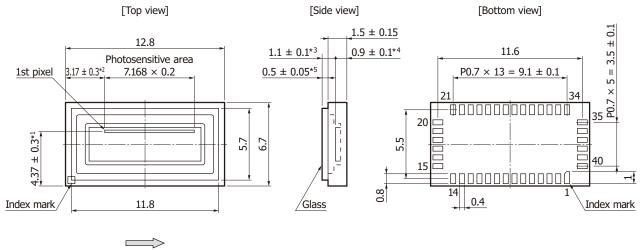
Parameter	Symbol	Min.	Тур.	Max.	Unit
Output signal rise time*17	tr(sigo)	-	10	12	ns
Output signal fall time*17	tf(sigo)	-	10	12	ns
SCLK-MISO output delay time	tSMD	-	-	25	ns

*17: Time for the output voltage to rise or fall between 10% and 90% when the load capacitance of the output terminal is 10 pF





Dimensional outline (unit: mm)



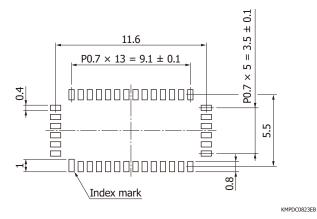
Direction of scan

Tolerance unless otherwise noted: ±0.2

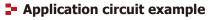
- *1: Distance from package edge to photosensitive area center
- *2: Distance from package edge to photosensitive area edge
- *3: Distance from glass surface to photosensitive surface
- *4: Distance from package bottom to photosensitive surface
- *5: Glass thickness

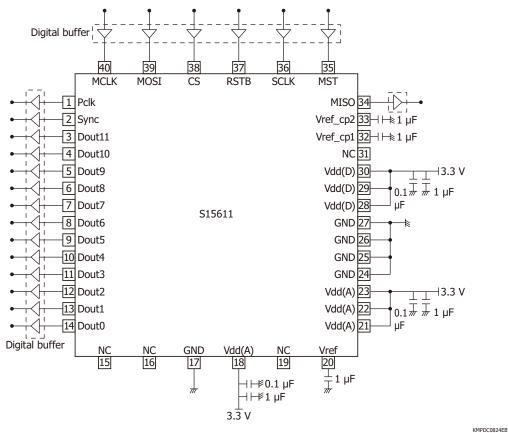
KMPDA0357EB

Recommended land pattern (unit: mm)









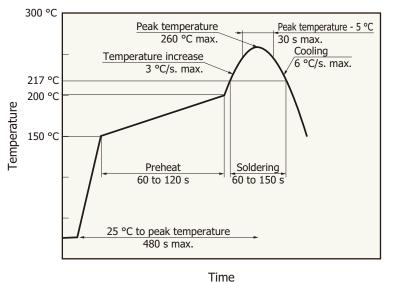
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Pin connections

Pin no.	Symbol	Description	I/O
1	Pclk	Pixel output sync signal	0
2	Sync	Frame sync signal	0
3	Dout11	Video output signal	0
4	Dout10	Video output signal	0
5	Dout9	Video output signal	0
6	Dout8	Video output signal	0
7	Dout7	Video output signal	0
8	Dout6	Video output signal	0
9	Dout5	Video output signal	0
10	Dout4	Video output signal	0
11	Dout3	Video output signal	0
12	Dout2	Video output signal	0
13	Dout1	Video output signal	0
14	Dout0	Video output signal	0
15	NC*18	No connection	-
16	NC*18	No connection	-
17	GND	Ground	-
18	Vdd(A)	Analog supply voltage (3.3 V)	I
19	NC*18	No connection	-
20	Vref*19	Bias voltage	0
21	Vdd(A)	Analog supply voltage (3.3 V)	I
22	Vdd(A)	Analog supply voltage (3.3 V)	I
23	Vdd(A)	Analog supply voltage (3.3 V)	I
24	GND	Ground	-
25	GND	Ground	-
26	GND	Ground	-
27	GND	Ground	-
28	Vdd(D)	Digital supply voltage (3.3 V)	I
29	Vdd(D)	Digital supply voltage (3.3 V)	I
30	Vdd(D)	Digital supply voltage (3.3 V)	I
31	NC*18	No connection	-
32	Vref_cp1*19	Bias voltage for charge pump circuit	0
33	Vref_cp2*19	Bias voltage for negative voltage circuit	0
34	MISO	SPI output signal	0
35	MST	Master start signal	I
36	SCLK	SPI clock signal	I
37	RSTB	SPI reset signal	I
38	CS	SPI selection signal	I
39	MOSI	SPI input signal	I
40	MCLK	Master clock signal	I

*18: Leave NC pins open; do not connect to GND. *19: Insert a 1 μ F capacitor between the terminal and GND.





Recommended reflow soldering conditions (typical example)

KMPDB0405EA

- This product supports lead-free soldering. After unpacking, store it in an environment at a temperature of 30 °C or less and a humidity of 60% or less, and perform soldering within 72 hours.
- The effect that the product receives during reflow soldering varies depending on the circuit board and reflow oven that are used. When you set reflow soldering conditions, check that problems do not occur in the product by testing out the conditions in advance.
- . The bonding portion between the ceramic base and the glass may discolor after reflow soldering, but this has no adverse effects on the hermetic sealing of the product.

Precautions

(1) Electrostatic countermeasures

This device has a built-in protection circuit against static electrical charges. However, to prevent destroying the device with electrostatic charges, take countermeasures such as grounding yourself, the workbench and tools to prevent static discharges. Also protect this device from surge voltages which might be caused by peripheral equipment.

(2) Input window

If dirt or dust adheres to the surface of the input window glass, the photoresponse uniformity will be lost. When cleaning, avoid rubbing the window surface with dry cloth, dry cotton swab or the like, since doing so may generate static electricity. Use soft cloth, paper, a cotton swab, or the like moistened with alcohol to wipe off dust and stain. Then blow compressed air so that no stain remains.

(3) UV light irradiation

This product is not designed to resist characteristic deterioration under UV light irradiation. Do not apply UV light irradiation.



Related information

www.hamamatsu.com/sp/ssd/doc_ja.html

- Precautions
- Disclaimer
- · Image sensors
- Surface mount type products

Technical information

· CMOS linear image sensors

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HAMAMATSU PHOTONICS K.K., Solid State Division

1126-1 Ichino-cho, Chuo-ku, Hamamatsu City, 435-8558 Japan, Telephone: (81)53-434-3311, Fax: (81)53-434-5184

1126-1 IChino-cho, Chuo-ku, Hamamatsu LICV, 452-8585 Japan, Ielephone: (1)082-31-0306, Fax: (1)908-231-0311, FGA. (01)20-45-45-0312, FGA. (01)20-45-45-032, FGA. (01)20-45-45-45-45-45, FGA. (01)20-45-45-45-45, FGA. (01)20-45-45-45-45, FGA. (01)20-45-45-45-45, FGA. (01)20-45-45-45, FGA. (01)20-45-45-45-45, FGA. (01)20-45-45-45, FGA. (01